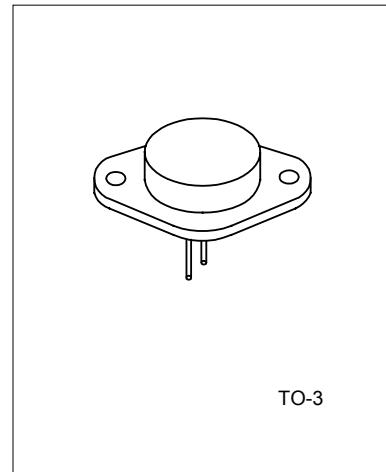


## COMPLEMENTARY SILICON TRANSISTORS

The 2N3773/2N6099 are power-base power transistors designed for high power audio, disk head positions and other linear applications. These device can be used in power switching circuits such as relay or solenoid drivers, DC to DC converters or inverters.

### FEATURES

- \*High safe operating area(100 tested)
- 150W and 100V
- \*Complement Characterized for linear operation
- \*High DC Current Gain and low saturation voltage
- $H_{fe}=15(8A/4V)$
- $V_{ce(sat)}=1.4V(I_c=8A, I_b=0.8A)$
- \*For Low Distortion Complementary Designs



### ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise specified)

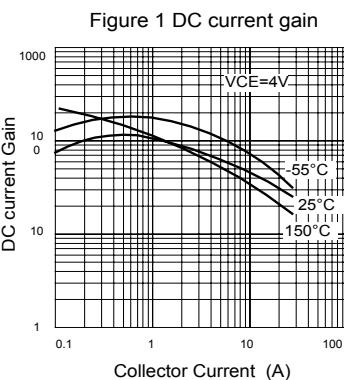
PARAMETERS	SYMBOL	VALUE	UNITS
Collector-base voltage	$V_{CBO}$	160	V
Collector-emitter voltage	$V_{CEO}$	140	V
Emitter-base voltage	$V_{EBO}$	7	V
Collector-emitter voltage	$V_{CEX}$	160	V
Total Power dissipation $T_c=25^\circ C$ Derate above $25^\circ C$	$P_c$	150 0.855	W W/ $^\circ C$
Collector current continuous Peak	$I_c$	16 30	A A
Base current continuous Peak	$I_B$	4 15	A A
Thermal resistance Junction to Case	$R_{\theta JC}$	1.17	$^\circ C/W$
Storage Temperature	$T_{STG}$	-65 ~ +200	$^\circ C$

## ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BVCBO	Ic=0.2A, Ib=0	140			V
Collector-Emitter Sustaining Voltage	BVCEX	Ic=0.1A, Vbe(OFF)=1.5V Rbe=100Ω	160			V
Collector-Emitter Sustaining Voltage	BVCER	Ic=0.1A Rbe=100Ω	150			V
Collector Cut-off Current	ICBO	Vcb=140V, Ie=0		2		mA
Emitter Cut-off Current	IEBO	Vbe=7V, Ic=0		5		mA
Collector Cut-off Current	ICEX	Vce=140V, Vbe(off)=1.5V Vce=140V, Vbe(off)=1.5V , Tc=150°C		2		mA
				10		mA
<b>OFF CHARACTERISTICS</b>						
DC current gain(note)	hFE1 hFE2	Vce=4V, Ic=8A Vce=4V, Ic=16A	15 5		60	
Collector-emitter saturation voltage	Vce(sat)	Ic=8A, Ib=800mA Ic=16A, Ib=3.2A			1.4 4	V
Base-emitter saturation voltage	Vbe(on)	Ic=8A, Vce=4V			2.2	V
<b>DYNAMIC CHARACTERISTICS</b>						
Small Signal Current Gain	hFE	Ic=1A, Vce=4V, f=1kHz	40			
Magnitude of common-Emitter small signal, short circuit forward current transfer ratio	hFE	Ic=1A, f=50kHz	4			
Second breakdown collector with base forward biased	Is/b	t=1s(non-repetitive), Vce=100V	1.5			A

## TYPICAL PARAMETERS PERFORAMCES

2N3773



2N6609

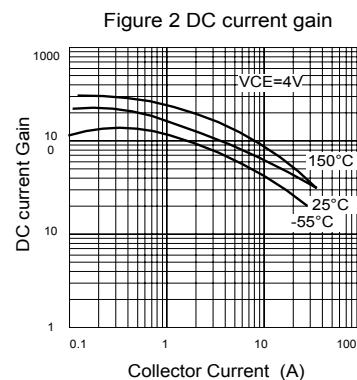


Figure 3 Collecotor saturation region

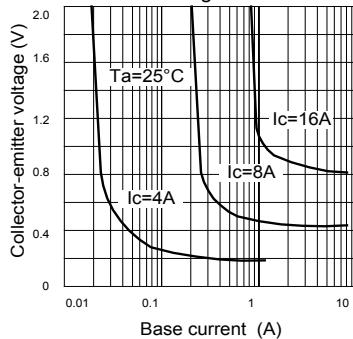


Figure 4 Collecotor saturation region

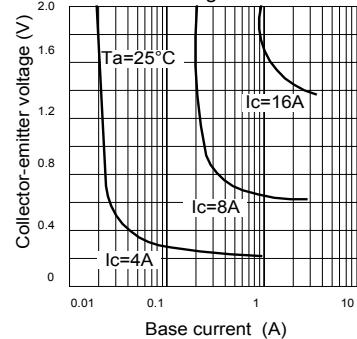


Figure 5 "ON" Voltage

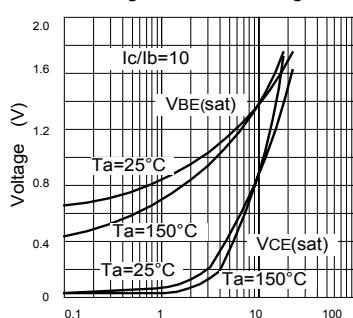
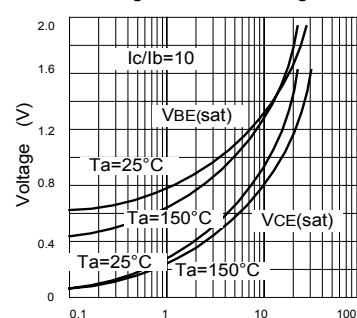


Figure 6 "ON" Voltage



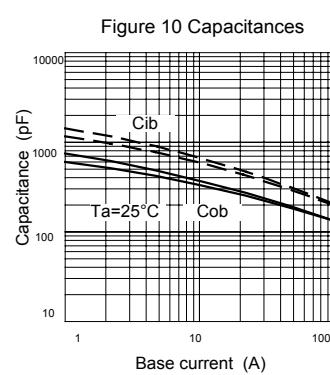
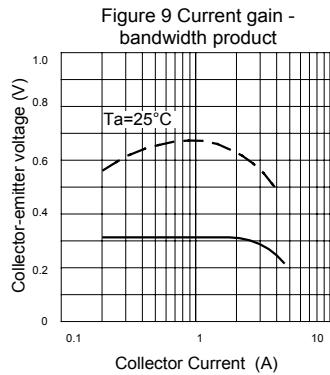
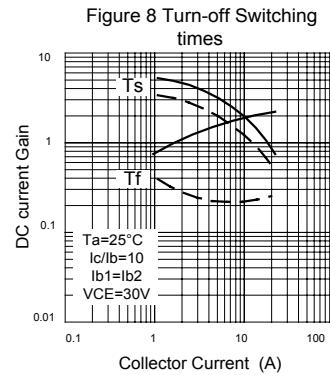
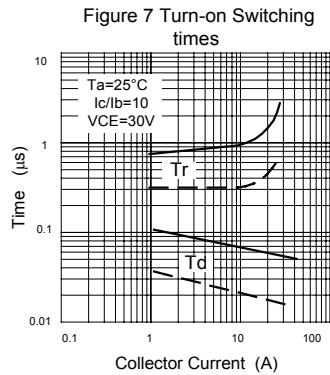
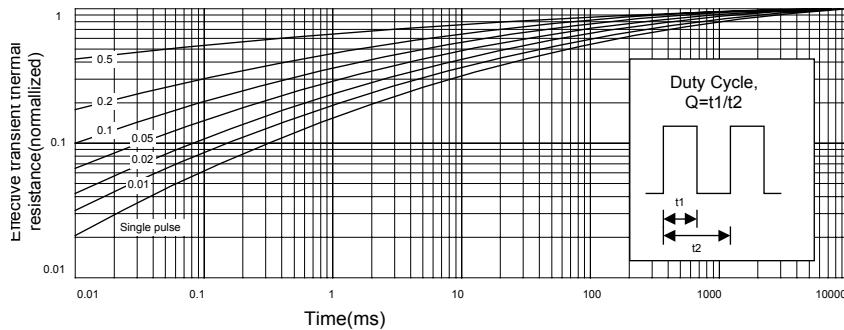


Figure 11 Thermal response



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